





#### **40V PNP LOW SATURATION SWITCHING TRANSISTOR**

#### **Features and Benefits**

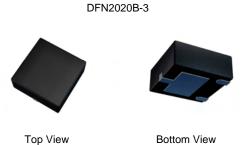
- BV<sub>CEO</sub> > -40V
- I<sub>C</sub> = -3A Continuous Collector Current
- Low Saturation Voltage (-220mV max @ -1A)
- $R_{SAT}$  = 104 m $\Omega$  for a low equivalent On-Resistance
- h<sub>FE</sub> specified up to -3A for high current gain hold up
- Low profile 0.6mm high package for thin applications
- $R_{\theta JA}$  efficient, 60% lower than SOT23
- 4mm<sup>2</sup> footprint, 50% smaller than SOT23
- Lead-Free, RoHS Compliant (Note 1)
- Halogen and Antimony Free. "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

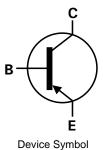
#### **Mechanical Data**

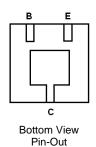
- Case: DFN2020B-3
- Case material: Molded Plastic. "Green" Molding Compound.
- Terminals: Pre-Plated NiPdAu leadframe.
- Nominal package height: 0.6mm
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Weight: 0.01 grams (approximate)

### **Applications**

- **MOSFET Gate Driving**
- **DC-DC Converters**
- **Charging Circuits**
- Power switches
- Motor control







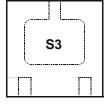
**Ordering Information (Note 3)** 

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTP720MATA	S3	7	8	3000

Notes:

- 1. No purposefully added lead.
- 2. Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com 3. For Packaging Details, go to our website at http://www.diodes.com.

### **Marking Information**



Top View

S3 = Product Type Marking code





# Maximum Ratings @TA = 25°C unless otherwise specified

Parameter		Symbol	Limit	Unit	
Collector-Base Voltage		V <sub>CBO</sub>	-50		
Collector-Emitter Voltage		$V_{CEO}$	-40	V	
Emitter-Base Voltage		V <sub>EBO</sub>	-7		
Peak Pulse Current		I <sub>CM</sub>	-4		
Continuous Collector Current	(Note 4)	1	-3	1 ,	
Continuous Conector Current	(Note 5)	IC	-3.3	^	
Base Current		l <sub>Β</sub>	-1		

## Thermal Characteristics @TA = 25°C unless otherwise specified

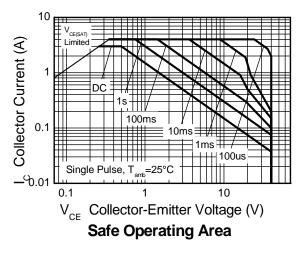
Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 4)		1.5 12	W
Linear Derating Factor	(Note 5)	PD	2.45 19.6	mW/°C
Thermal Resistance, Junction to Ambient	(Note 4)	83		
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\thetaJA}$	51	°C/W
Thermal Resistance, Junction to Lead (Note 6)		$R_{ heta JL}$	16.8	
Operating and Storage Temperature Range	T <sub>J.</sub> T <sub>STG</sub>	-55 to +150	°C	

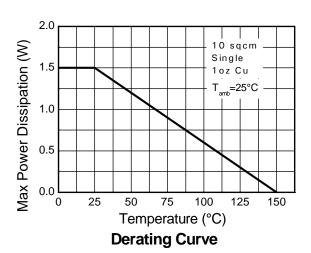
Notes:

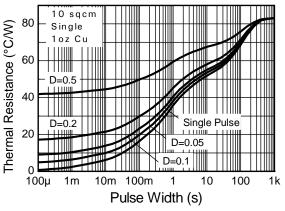
- For a device surface mounted on 31mm x 31mm (10cm²) FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition. The entire exposed collector pad is attached to the heatsink.
  Same as note (4), except the device is measured at t ≤ 5 sec.
- 6. For a single device, thermal resistance from junction to solder-point (at the end of the drain lead).

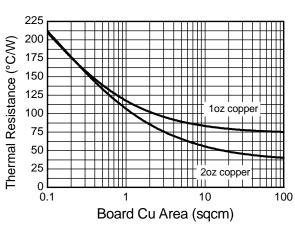


### **Thermal Characteristics**



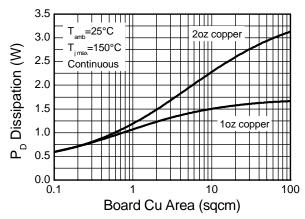






**Transient Thermal Impedance** 

Thermal Resistance v Board Area



Power Dissipation v Board Area





## Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

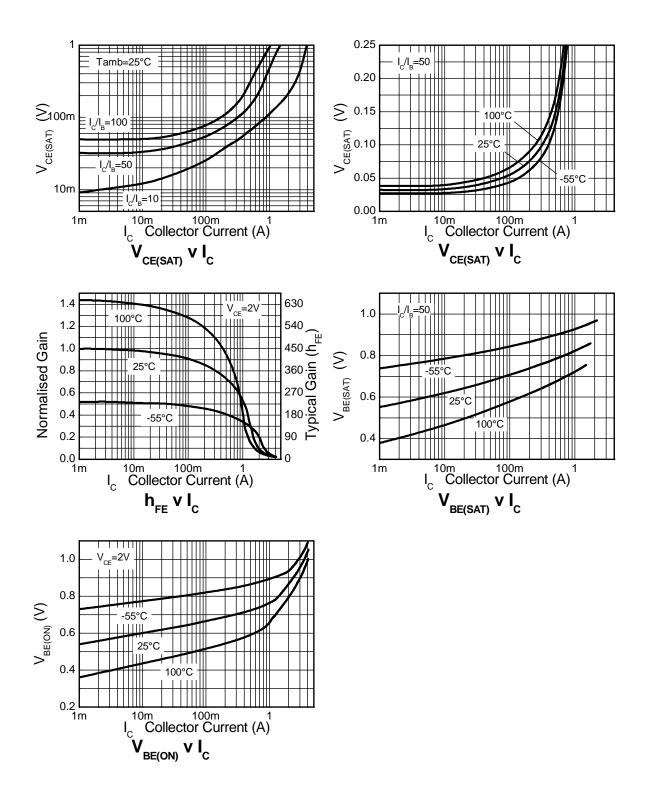
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-50	-80	-	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 7)	BV <sub>CEO</sub>	-40	-70	-	V	$I_C = -10 \text{mA}$
Emitter-Base Breakdown Voltage	$BV_{EBO}$	-7	-8.5	-	V	$I_E = -100 \mu A$
Collector Cutoff Current	I <sub>CBO</sub>	-	-	-100	nA	$V_{CB} = -40V$
Emitter Cutoff Current	I <sub>EBO</sub>	-	-	-100	. nA	$V_{EB} = -6V$
Collector Emitter Cutoff Current	I <sub>CES</sub>	-	-	-100	nA	V <sub>CES</sub> = -32V
Static Forward Current Transfer Ratio (Note 7)	h <sub>FE</sub>	300 300 180 60 12	480 450 290 130 22	- - - -	-	$\begin{split} I_C &= -10 \text{mA}, \ V_{CE} = -2 \text{V} \\ I_C &= -100 \text{mA}, \ V_{CE} = -2 \text{V} \\ I_C &= -1A, \ V_{CE} = -2 \text{V} \\ I_C &= -1.5 \text{A}, \ V_{CE} = -2 \text{V} \\ I_C &= -3 \text{A}, \ V_{CE} = -2 \text{V} \end{split}$
Collector-Emitter Saturation Voltage (Note 7)	V <sub>CE(sat)</sub>	-	-25 -150 -195 -210 -260	-40 -220 -300 -300 -370	mV	$\begin{split} I_C = -0.1A, \ I_B = -10 \text{mA} \\ I_C = -1A, \ I_B = -50 \text{mA} \\ I_C = -1.5A, \ I_B = -100 \text{mA} \\ I_C = -2A, \ I_B = -200 \text{mA} \\ I_C = -2.5A, \ I_B = -250 \text{mA} \end{split}$
Base-Emitter Turn-On Voltage (Note 7)	$V_{BE(on)}$	-	-0.89	-0.95	V	$I_C = -2.5A$ , $V_{CE} = -2V$
Base-Emitter Saturation Voltage (Note 7)	V <sub>BE(sat)</sub>	-	-0.97	-1.05	V	$I_C = -2.5A$ , $I_B = -250mA$
Output Capacitance	C <sub>obo</sub>	-	19	25	pF	V <sub>CB</sub> = -10V. f = 1MHz
Transition Frequency	f <sub>T</sub>	150	190	-	MHz	V <sub>CE</sub> = -10V, I <sub>C</sub> = -50mA, f = 100MHz
Turn-On Time	ton	-	40	-	ns	V <sub>CC</sub> = -15V, I <sub>C</sub> = -0.75A
Turn-Off Time	t <sub>off</sub>	-	435	-	ns	$I_{B1} = I_{B2} = -15 \text{mA}$

Notes: 7. Measured under pulsed conditions. Pulse width  $\leq$  300  $\mu$ s. Duty cycle  $\leq$  2%.



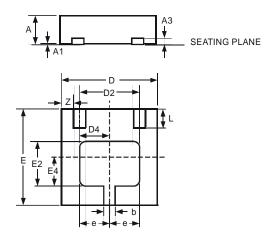


## **Typical Electrical Characteristics**



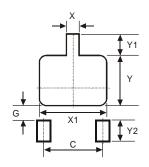


# **Package Outline Dimensions**



DFN2020B-3					
Dim	Min	Max	Тур		
Α	0.57	0.63	0.60		
A1	0	0.05	0.02		
А3	_	_	0.152		
b	0.20	0.30	0.25		
D	1.95	2.075	2.00		
D2	1.22	1.42	1.32		
D4	0.56	0.76	0.66		
е		_	0.65		
Е	1.95	2.075	2.00		
E2	0.79	0.99	0.89		
E4	0.48	0.68	0.58		
L	0.25	0.35	0.30		
Z		_	0.225		
All Dimensions in mm					

# **Suggested Pad Layout**



Dimensions	Value (in mm)			
С	1.30			
G	0.24			
Х	0.35			
X1	1.52			
Y	1.09			
Y1	0.47			
Y2	0.50			





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